2SD2225

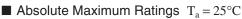
Silicon NPN epitaxial planar type

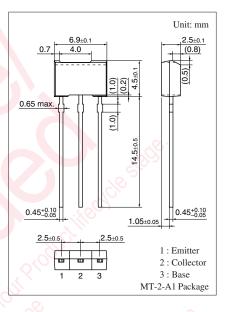
For low-frequency amplification

Features

- \bullet High collector-emitter voltage (Base open) $V_{\text{CEO}}\,\text{of}\,120\,\text{V}$
- Optimum for low-frequency driver amplification
- Allowing supply with the radial taping

Absolute Maximum Ratings $T_a = 25^{\circ}C$						
Parameter	Symbol	Rating	Unit			
Collector-base voltage (Emitter open)	r open) V _{CBO} 120		v			
Collector-emitter voltage (Base open)	V _{CEO}	120	V			
Emitter-base voltage (Collector open)	V _{EBO}	5	V			
Collector current	I _C	0.5	А			
Peak collector current	I _{CP}	1	А			
Collector power dissipation *	P _C	1	W			
Junction temperature	Tj	150	°C			
Storage temperature	T _{stg}	-55 to +150	°C			





Note) *: Printed circuit board: Copper foil area of 1 cm² or more, and the board thickness of 1.7 mm for the collector portion

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Мах	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 0.1 \text{ mA}, I_{\rm B} = 0$	120	0		V
Emitter-base voltage (Collector open)	V _{EBO}	$I_{\rm C} = 10 \ \mu {\rm A}, I_{\rm C} = 0$	5			V
Forward current transfer ratio *1	h _{FE1} *2	$V_{CE} = 10 \text{ V}, I_C = 150 \text{ mA}$	90		330	
	h _{FE2}	$V_{CE} = 5 \text{ V}, I_C = 500 \text{ mA}$	50			
	h _{FE3}	$V_{CE} = 5 \text{ V}, I_{C} = 100 \text{ mA}$	100			
Collector-emitter saturation voltage *1	V _{CE(sat)}	$I_{\rm C} = 300 \text{ mA}, I_{\rm B} = 30 \text{ mA}$		0.15	1.00	V
Base-emitter saturation voltage *1	V _{BE(sat)}	$I_{\rm C} = 300 \text{ mA}, I_{\rm B} = 30 \text{ mA}$		0.9	1.2	V
Transition frequency *1	f _T	$V_{CB} = 10 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$		200		MHz
Collector output capacitance (Common base, input open circuited)	C _{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		11.5	20.0	pF

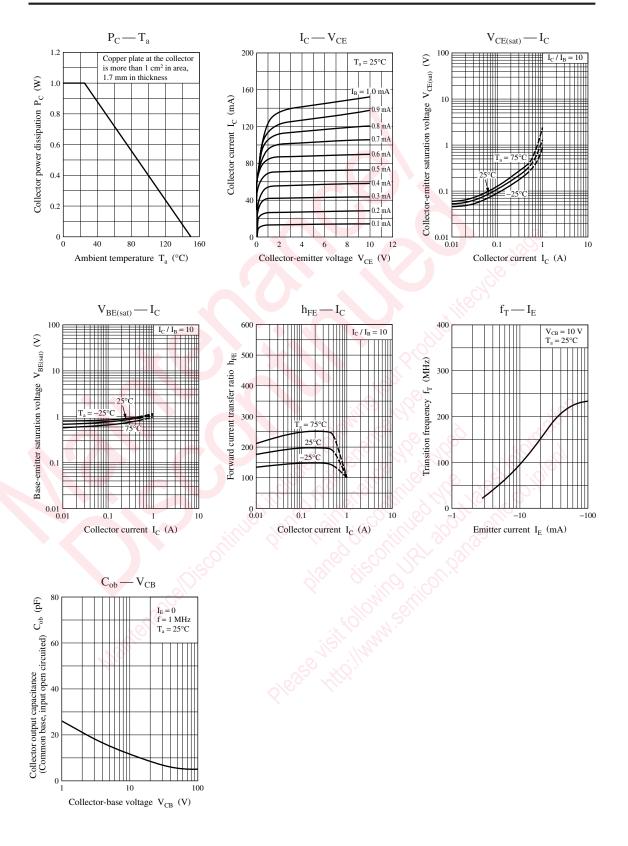
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *1: Pulse measurement

*2: Rank classification

Rank	Q	R	S
h _{FE1}	90 to 155	130 to 220	185 to 330

Panasonic



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